

WHAT IS CLAIMED IS:

1. A memory module for operation in a data memory system, comprising:
 - a plurality of data memory devices for storing useful data;
 - at least one buffer device connected to the data memory devices at least via data lines, and serving to condition at least data signals transferred on the data lines between the data memory devices and a memory checking device of the data memory system; and
 - at least one buffer and error checking module, which in each case integrates a buffer device and a data memory device for storing redundancy data operable to detect and to correct erroneous data in a common device housing.
2. The memory module of claim 1, wherein each of the buffer and error checking modules is connected to an even number of data memory devices for storing the useful data.
3. The memory module of claim 2, wherein the data memory devices are arranged symmetrically with respect to the buffer and error checking module.
4. The memory module of claim 1, wherein the buffer and error checking module has an error detecting unit operable, during a transfer of useful data to the memory module, to form and to store the redundancy data and, during a transfer of useful data to the memory checking device, to form check data from the useful data to be transferred and also to compare respectively corresponding redundancy data and check data.

5. The memory module of claim 4, wherein the buffer and error checking module has an error correction unit operable to correct erroneous useful data on the basis of respectively corresponding redundancy data and check data.
6. The memory module of claim 5, wherein the memory module is absent a contact device assigned to a data line for transferring redundancy data.
7. The memory module of claim 5, wherein the memory module has an error signaling unit operable to transfer information on error events to the memory checking device.
8. The memory module of claim 5, wherein the buffer and error checking module has an error evaluation unit operable to identify and to mask out defective memory cells in the data memory devices.
9. The memory module of claim 1, wherein the data memory devices are configured as DRAM modules.
10. The memory module of claim 1, wherein the data memory devices comprise a DDR interface.
11. The memory module of claim 1, wherein the maximum dimensions of the memory module are about 1.2 inches × 5.25 inches.

12. A buffer and error checking module for memory modules operated in data memory systems, comprising:

connecting devices;

a buffer/redriver formed in a semiconductor substrate and operable to condition at least data signals that are transferred to and from the memory modules; and

a memory cell array formed in the semiconductor substrate as an error data memory.

13. The buffer and error checking module of claim 12, further comprising an error detecting unit operable, during a transfer of useful data to the memory module, to form and to store redundancy data and, during a transfer of useful data to a memory checking device of the data memory system, to compare the stored redundancy data with check data formed from the useful data to be transferred.

14. The buffer and error checking module of claim 13, further comprising an error correction unit operable to correct erroneous useful data on the basis of respectively corresponding redundancy data and check data.

15. The buffer and error checking module of claims 13, further comprising an error signaling unit operable to transfer information on error events to the data memory system.

16. The buffer and error checking module of claim 13, further comprising an error evaluation unit operable to identify and to mask out defective memory cells in data memory devices connected to the buffer and error checking module.

17. A method for operating a memory module having a plurality of data memory devices for storing useful data and at least one buffer and error checking module in a data memory system, the method comprising:

receiving data signals of useful data transferred to the memory module and conditioning the data signals with the buffer and error checking module;

forming, in the buffer and error checking module, a corresponding set of redundancy data with respect to the useful data;

storing the useful data in the data memory devices;

storing the respectively corresponding set of redundancy data in the buffer and error checking module;

forming in the buffer and error checking module, during a transfer of stored useful data from the data memory devices to a memory checking device of the data memory system, a corresponding set of check data;

detecting, through a comparison of respectively corresponding redundancy data and check data, data errors that have occurred in the useful data and correcting any such errors on a case by case basis; and

transferring corrected and essentially error-free useful data to the memory checking device.

18. The method of claim 17, further comprising signaling an occurrence of a data error in the useful data to the memory checking device of the data memory system.

19. The method of claim 17, further comprising optimizing a data memory system by:
providing a redundancy bus system in precursor systems on a system board between a
memory checking device and the memory module;
registering transfer errors in the bus system and analyzing, in the precursor systems, the
transfer errors by the memory checking device with the aid of the redundancy bus system;
developing, on the basis of an analysis of transfer errors occurring between the memory
checking device and the memory module, a bus system of respective precursor systems in a
direction of a minimum number of transfer errors; and
providing the data memory system with the bus system developed for a minimum number
of transfer errors.

20. The method of claim 19, wherein the data memory system is provided without the
redundancy bus system.